



DN0150ADJ / DN0150BDJ

DUAL NPN SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Ideally Suited for Automated Assembly Processes
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- **Ultra Small Package**

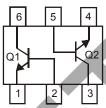
Mechanical Data

- Case: SOT-963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.0027 grams (approximate)

SOT-963



Top View



Device Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | 60 | V |
| Collector-Emitter Voltage | V _{CEO} | 50 | V |
| Emitter-Base Voltage | V _{EBO} | 5 | V |
| Collector Current – Continuous | lc | 100 | mA |
| Base Current | l _B | 30 | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 3) | P _D | 300 | mW |
| Thermal Resistance, Junction to Ambient (Note 3) | $R_{	heta JA}$ | 417 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics @TA = 25°C unless otherwise specified

| Characteristi | C | Symbol | Min | Тур | Max | Unit | Test Condition |
|--------------------------------------|-----------|----------------------|-----|------|------|---------------|--|
| OFF CHARACTERISTICS (Note 4) | | | | | | | |
| Collector-Base Breakdown Voltage | | V(BR)CBO | 60 | _ | _ | V | $I_C = 10 \mu A, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | e | V(BR)CEO | 50 | _ | _ | V | $I_{C} = 1mA, I_{B} = 0$ |
| Emitter-Base Breakdown Voltage | | V(BR)EBO | 5 | _ | _ | V | $I_E = 10\mu A, I_C = 0$ |
| Collector Cut-Off Current | | I _{CBO} | 1 | 1 | 0.1 | μΑ | $V_{CB} = 60V, I_{E} = 0$ |
| Emitter Cut-Off Current | | I _{EBO} | _ | _ | 0.1 | μΑ | $V_{EB} = 5V, I_{C} = 0$ |
| ON CHARACTERISTICS (Note 4) | • | | | | | | |
| Collector-Emitter Saturation Voltage | | V _{CE(SAT)} | _ | 0.10 | 0.25 | V | I _C = 100mA, I _B = 10mA |
| DC Current Gain | DN0150ADJ | | 120 | _ | 240 |)/ 0)/ 0: A | |
| | DN0150BDJ | h _{FE} | 200 | _ | 400 | _ | $V_{CE} = 6V$, $I_C = 2mA$ |
| SMALL SIGNAL CHARACTERISTIC | CS | | | | | | |
| Transition Frequency | | f⊤ | 60 | I | | MHz | $V_{CE} = 10V, I_{E} = -1mA$ f = 30MHz |
| Output Capactiance | | C _{ob} | _ | 1.3 | _ | pF | V _{CB} = 10V, I _E = 0, f = 1MHz |

Notes:

- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB with minimum recommended pad layout.
- 4. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤2%



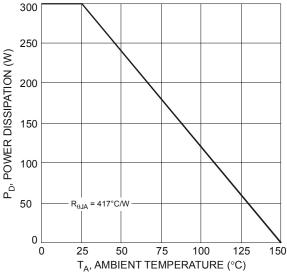
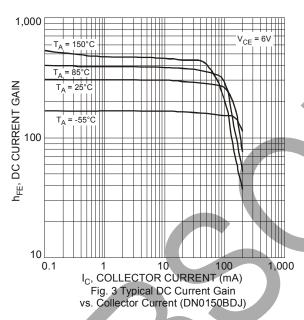
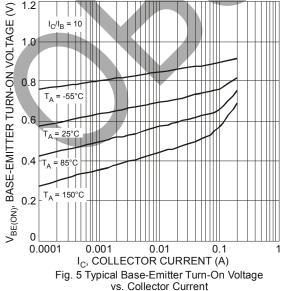


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)





1,000 Pw = 10ms

Pw = 10ms

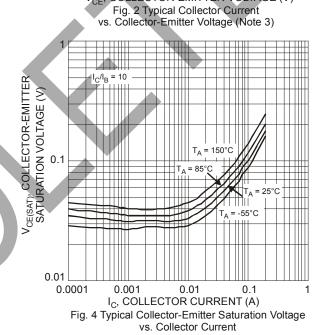
100

Pw = 10ms

100

100

-V_{CE}, COLLECTOR-EMITTER VOLTAGE (V)



1.2

UNDER 1.0

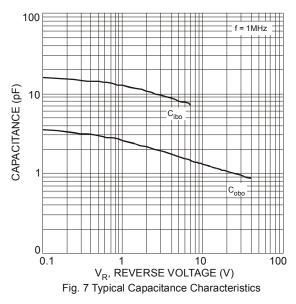
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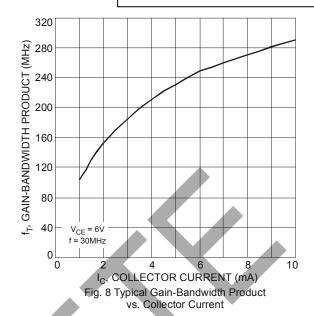
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Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

DIODES.

DN0150ADJ / DN0150BDJ



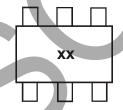


Ordering Information (Note 5)

| Device | Packaging | Shipping |
|-------------|-----------|--------------------|
| DN0150ADJ-7 | SOT-963 | 10,000/Tape & Reel |
| DN0150BDJ-7 | SOT-963 | 10,000/Tape & Reel |

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

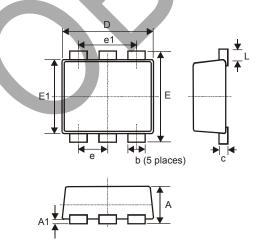
Marking Information



xx= Product Type Marking Code: T3 = DN0150ADJ

T4 = DN0150ADJ

Package Outline Dimensions



| SOT-963 Dim Min Max Typ | | | | | |
|-------------------------|----------|----------|-------|--|--|
| Dim | Min | /lin Max | | | |
| Α | 0.40 | 0.50 | 0.45 | | |
| A1 | 0 | 0.05 | - | | |
| С | 0.077 | 0.177 | 0.127 | | |
| D | 0.95 | 1.05 | 1.00 | | |
| Е | 0.95 | 1.05 | 1.00 | | |
| E1 | 0.75 | 0.85 | 0.80 | | |
| L | 0.05 | 0.15 | 0.10 | | |
| b | 0.10 | 0.20 | 0.15 | | |
| е | 0.35 Typ | | | | |
| e1 | 0.70 Typ | | | | |
| All Dimensions in mm | | | | | |



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